PΛN	ĴΪΤ
	SEMI CONDUCTOR

60V N-Channel Enhancement Mode MOSFET

Current

7.5 A

Features

Voltage

• RDS(ON), VGS@10V, ID@7.5A<21mΩ

60 V

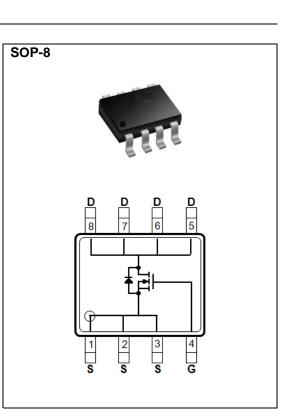
- RDS(ON), VGS@4.5V, ID@4.0A<24mΩ
- Advanced Trench Process Technology
- High density cell design for ultra low on-resistance
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

Mechanical Data

- Case: SOP-8 package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0029 ounces, 0.083 grams
- Marking: L9436A



PARAME	TER	SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	60	V
Gate-Source Voltage		V _{GS}	<u>+</u> 20	V
Continuous Drain Current	T _A =25°C		7.5	
	T _A =70°C	I _D	6.0	A
Pulsed Drain Current (Note 1)		I _{DM}	30	А
Power Dissipation	T _A =25°C		2.5	
	T _A =70°C	P _D	1.6	W
Single Pulse Avalanche Energy	Pulse Avalanche Energy ^(Note 5) E _{AS}		31.3	mJ
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150	°C
Typical Thermal resistance - Junction to Ambient, t \leq 10s ^(Note 6)		R _{θJA}	50	°C/W



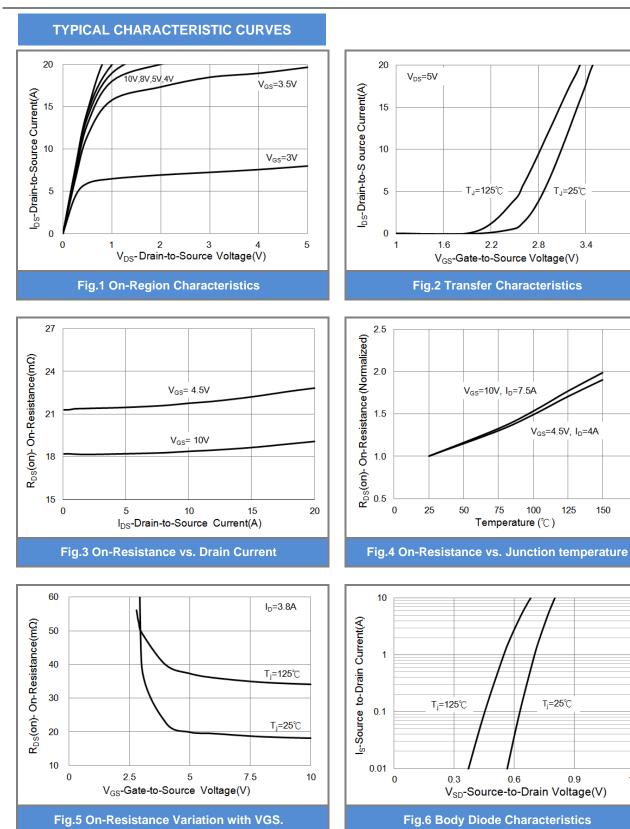


Electrical Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	V _{GS} =0V,I _D =250uA	60	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250$ uA	1.0	1.73	2.5	V
Drain-Source On-State Resistance	$R_{DS(on)}$	V _{GS} =10V,I _D =7.5A	-	18	21	mΩ
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =4.5V,I _D =4.0A	-	21	24	mΩ
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V,V _{GS} =0V	-	-	1.0	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V,V _{DS} =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 7)		-		_		_
Total Gate Charge	Q_{g}	V_{DS} =30V, I _D =7.5A, V_{GS} =10V ^(Note 1,2)	-	28	-	
Gate-Source Charge	Q_gs		-	3.5	-	nC
Gate-Drain Charge	Q_gd		-	6.5	-	
Input Capacitance	Ciss	V _{DS} =20V, V _{GS} =0V, f=1.0MHZ	-	1680	-	_
Output Capacitance	Coss		-	115	-	pF
Reverse Transfer Capacitance	Crss		-	85	-	
Turn-On Delay Time	td _(on)	$V_{DD}=30V, I_{D}=1A,$ $V_{GS}=10V, R_{G}=6\Omega$ (Note 1.2)	-	7.2	-	_
Turn-On Rise Time	tr		-	38	-	
Turn-Off Delay Time	td _(off)		-	34	-	ns
Turn-Off Fall Time	tf		-	8.2	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	I _S		-	-	7.5	А
Diode Forward Current	'3				1.0	
Diode Forward Voltage	V_{SD}	I _S =1.0A, V _{GS} =0V	-	0.7	1.0	V

NOTES :

- 1. Pulse width</br>
- 2. Essentially independent of operating temperature typical characteristics.
- 3. The maximum current rating is package limited.
- 4. Repetitive rating, pulse width limited by junction temperature TJ(MAX)=150°C. Ratings are based on low frequency and duty cycles to keep initial TJ =25°C.
- 5. The test condition is L=0.1mH, $I_{AS}{=}25A,\,V_{DD}{=}25V,\,V_{GS}{=}10V$
- 6. R_{®JA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 7. Guaranteed by design, not subject to production testing.

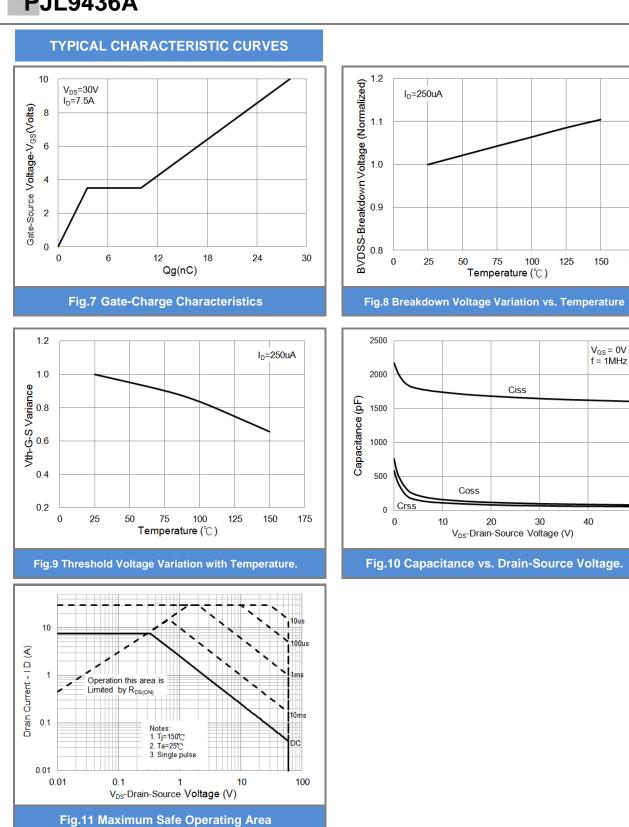


4

150

175

1.2





175

50

PJL9436A TYPICAL CHARACTERISTIC CURVES Z_{TH-JA} Normalized Transient Thermal Impedance D=0.5 0.2 0.1 0.05 0.02 $\begin{array}{l} T_{J,PK}{=}Ta{+}P_{DM}{}^{*}Z_{TH{-}JA}{}^{*}R_{TH{-}JA}\\ R_{TH{-}JA}=50^{\circ}\mathbb{C}\,/W\\ Ta=25^{\circ}\mathbb{C} \end{array}$ 0.01

0.001

Single Pulse

0.0001

PANJIT SEMI CONDUCTOR

0.00001



0.01

t, Pulse Width (Sec)

Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width

DN L

0.1

PW 1

 $D = \frac{PW}{T}$

10

1

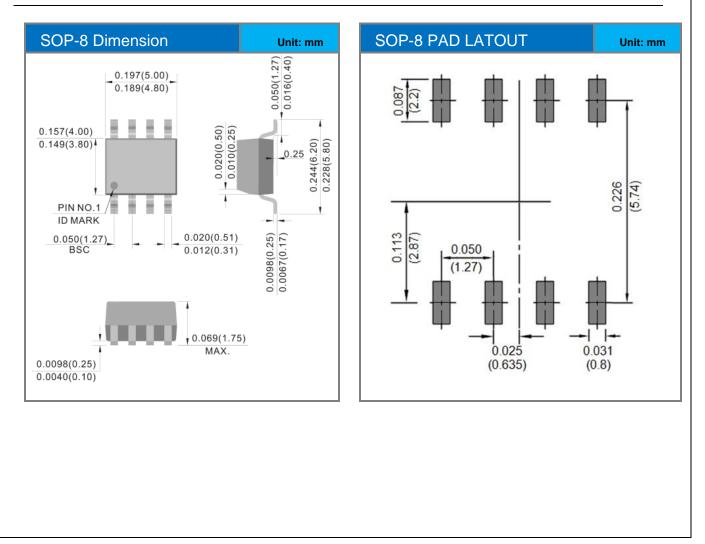




PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJL9436A_R2_00001	SOP-8	2.5K pcs / 13" reel	L9436A	Halogen free

Packaging Information & Mounting Pad Layout





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